

Transistor

Panasonic

2SB0710, 2SB0710A (2SB710, 2SB710A)

Silicon PNP epitaxial planer type

For general amplification

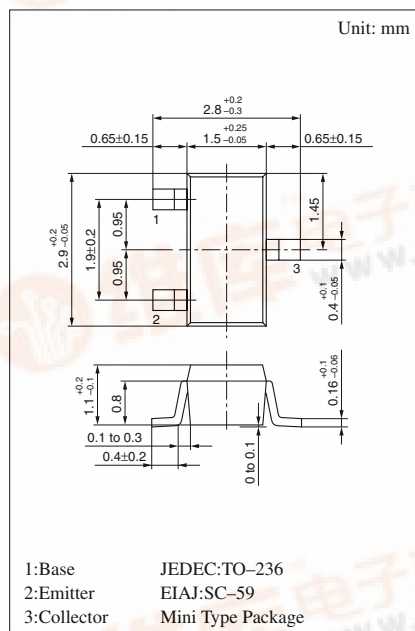
Complementary to 2SD0602 (2SD602) and 2SD0602A (2SD602A)

Features

- Large collector current I_C .
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	-30	V
2SB0710A		-60	
Collector to emitter voltage	V _{CEO}	-25	V
2SB0710A		-50	
Emitter to base voltage	V _{EBO}	-5	V
Peak collector current	I _{CP}	-1	A
Collector current	I _C	-0.5	A
Collector power dissipation	P _C	200	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 ~ +150	°C



Marking symbol : C(2SB0710)
D(2SB0710A)

Electrical Characteristics (Ta=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I _{CBO}	V _{CB} = -20V, I _E = 0			-0.1	μA
Collector to base voltage	V _{CBO}	I _C = -10μA, I _E = 0	-30			V
			-60			
Collector to emitter voltage	V _{CEO}	I _C = -10mA, I _B = 0	-25			V
			-50			
Emitter to base voltage	V _{EBO}	I _E = -10μA, I _C = 0	-5			V
Forward current transfer ratio	h _{FE1} *1	V _{CE} = -10V, I _C = -150mA*2	85		340	
	h _{FE2}	V _{CE} = -10V, I _C = -500mA*2	40			
Collector to emitter saturation voltage	V _{CE(sat)}	I _C = -300mA, I _B = -30mA*2		-0.35	-0.6	V
Base to emitter saturation voltage	V _{BE(sat)}	I _C = -300mA, I _B = -30mA*2		-1.1	-1.5	V
Transition frequency	f _T	V _{CB} = -10V, I _E = 50mA, f = 200MHz		200		MHz
Collector output capacitance	C _{ob}	V _{CB} = -10V, I _E = 0, f = 1MHz		6	15	pF

*1h_{FE1} Rank classification

*2 Pulse measurement

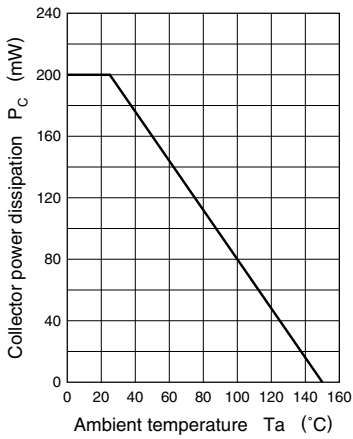
Rank	Q	R	S
h _{FE1}	85 ~ 170	120 ~ 240	170 ~ 340
Marking	2SB0710	CR	CS
Symbol	2SB0710A	DR	DS

Note.) The Part numbers in the Parenthesis show conventional part number.

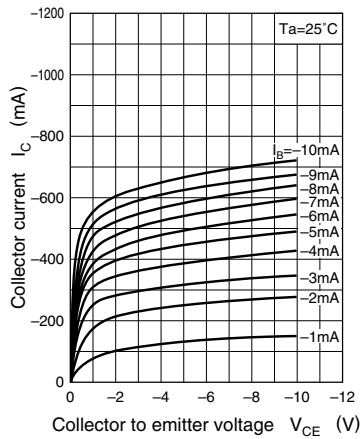
Transistor

2SB0710, 2SB0710A

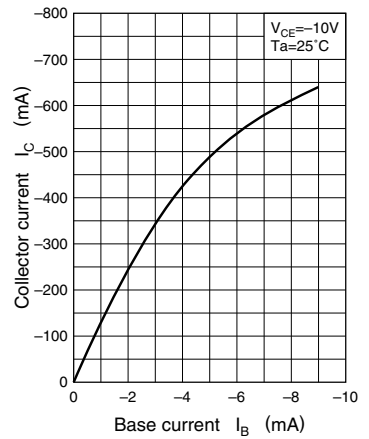
$P_C - T_a$



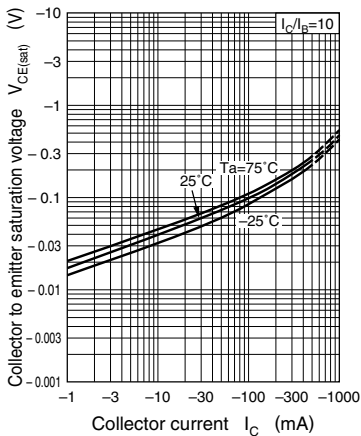
$I_C - V_{CE}$



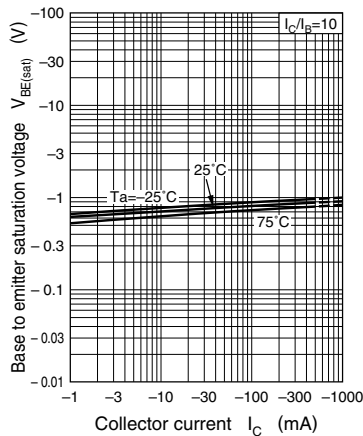
$I_C - I_B$



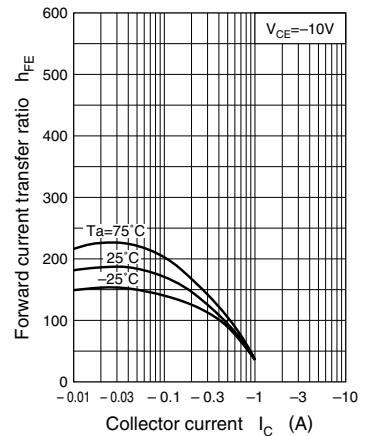
$V_{CE(sat)} - I_C$



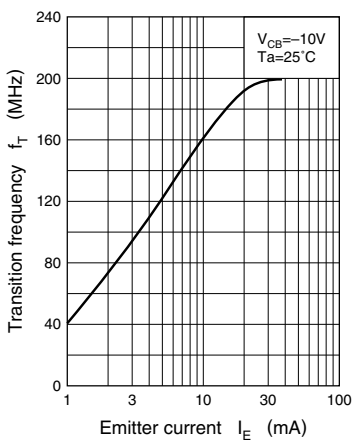
$V_{BE(sat)} - I_C$



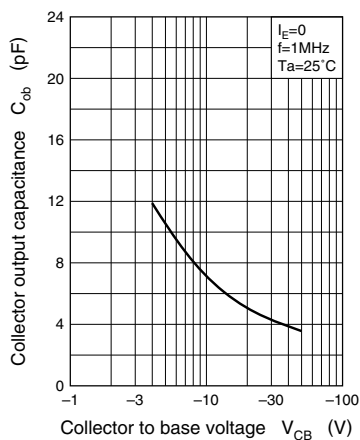
$h_{FE} - I_C$



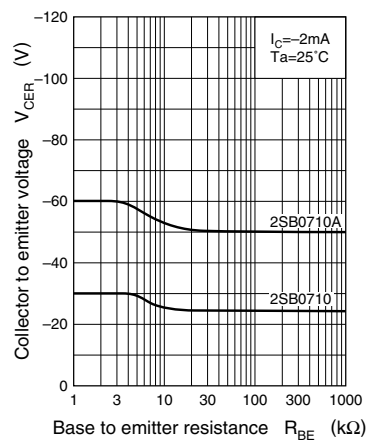
$f_T - I_E$



$C_{ob} - V_{CB}$



$V_{CER} - R_{BE}$



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